

Improved synthesis of free bases of 5,10,15,20-tetraaryl-5,15-diazaporphyrinoid for conversion to silicon(IV) complexes

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Abstract

We report herein an improved method for the quantitative preparation of free bases of 5,10,15,20-tetraaryl-5,15-diazaporphyrinoid (TADAP) using Me_3SiBr –MeOH to treat the corresponding zinc(II) complexes. Metallation of the free base with HSiCl₃ followed by Si–X metathesis with SbF₃ and redox reactions afforded difluorosilicon(IV) complexes of TADAP.

Keywords: diazaporphyrin, free base, silicon(IV) complex.

Graphical Abstract



Free bases of 5,10,15,20-tetraaryl-5,15-diazaporphyrinoid (TADAP) were easily prepared using Me₃SiBr–MeOH to treat the corresponding zinc(II) complexes. The first examples of difluorosilicon(IV) complexes of TADAP were successfully prepared from the free base and trichlorosilane.

1. Introduction

Porphyrins are well-known redox-active 18π -electron aromatic molecules, and their oxidized/reduced species have attracted considerable attention because they are involved in various phenomena, including electron/energy-transfer processes, semiconduction, and aromaticity–antiaromaticity switching.¹ However, 19π -electron radical anions and 20π -electron dianions of porphyrin are extremely unstable in air, making isolation and characterization of these anionic species difficult. Several research groups have developed charge-shifting methods to stabilize 19π - and 20π -electron porphyrins, which can

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Scheme 1. Synthesis of TADAP free bases.

then be isolated in the uncharged state.²⁻⁸ Recently, we prepared the first examples of metal complexes of 5,10,15,20-tetraaryl-5,15-diazaporphyrinoid (MTADAP; M = Co, Ni, Cu, Zn) by metal-templated annulation of the corresponding metal(II)-bis(dipyrrin) complexes.9-11 Notably, most MTADAPs in the 20 π - and 19 π -electron forms are stable in air and exhibit characteristic optical, magnetic, and electrochemical properties depending on the central metal. However, the metal-templated annulation method is currently applicable only to the above four metals. Therefore, it is important to develop a general protocol for the metal complexation of free bases of TADAP (H2TADAP). In our previous work, H₂TADAPs were obtained in moderate yields by demetallation of the corresponding ZnTADAPs, referring to the Yorimitsu–Osuka protocol for the synthesis of porphyrins.¹² Unfortunately, this method requires large excess amounts of a Grignard reagent and trifluoroacetic acid, sometimes contaminating the reaction system with byproducts. In this study, we developed a more convenient and reproducible protocol to obtain H₂TADAP. The structure, aromaticity, and optical and redox properties of the newly prepared silicon(IV) complexes of TADAP were also revealed.

2. Results and discussion

ZnTADAPs 1Zn-a and 2Zn-a,b were prepared according to the previously-reported method.¹⁰ Scheme 1 and Table 1 summarize the results of reacting 1Zn-a and 2Zn-a,b with several acids. The reactions were monitored using high-resolution mass (HRMS) spectrometry and ultraviolet/visible/near-infrared (UV/vis/NIR) absorption spectroscopy. When 1Zn-a was treated with aqueous solutions of HCl, HBr, and H₂SO₄ in CH₂Cl₂ at room temperature, demetallation did not occur (Table 1, entries 1 to 3). By contrast, when trimethylsilyl halides $(Me_3SiX; X = Cl, Br, I)$ were used instead of HX aq, demetallation of 1Zn-a took place to generate desired H₂TADAP 1H₂-a together with inseparable byproducts (entries 4 to 6; The ¹H NMR and HRMS data suggested that small amounts of halogenated TADAPs were included, although their structures could not be identified. These byproducts may be formed via nucleophilic attack of the halide ions onto the cationic TADAP ring). Moreover, Me₃SiOTf was ineffective in promoting demetallation (entry 7). When 2Zn-a was used as the substrate, formation of the byproducts was completely suppressed and high-purity 1H2-a was obtained (entries 8, 9). Furthermore, the yield of 1H2-a was improved by adding

Table 1. Results for demetallation of ZnTADAPs.

Entry	1/2	Acids (equiv.)	Time (h)	Yield (%) ^{a,b}
1	1Zn-a	HCl aq ^c	2	N.r.
2	1Zn-a	HBr aq ^d	2	N.r.
3	1Zn-a	H_2SO_4 aq ^e	2	N.r.
4	1Zn-a	Me ₃ SiCl (70)	32	ca.50 ^f
5	1Zn-a	Me ₃ SiBr (5)	3	ca.80 ^f
6	1Zn-a	$Me_3SiI(5)$	3	ca.50 ^f
7	1Zn-a	Me ₃ SiOTf (5)	76	N.r.
8	2Zn-a	Me ₃ SiCl (70)	18	60
9	2Zn-a	Me ₃ SiBr (20)	5	75
10	2Zn-a	Me ₃ SiBr–MeOH (30)	5	98 ^g
11	2Zn-a	Me ₃ SiCl–MeOH (70)	5	74
12	2Zn-b	Me ₃ SiBr–MeOH (30)	12	82 ^g

N.r., No reaction.

^bNMR yields of 2H₂, which were obtained by treatment of the product mixtures including 1H₂ with CoCp₂, are listed unless otherwise noted. ^cca. 35%.

^dca. 50%. ^eca. 95%.

ca. 95%.

^fUnidentified byproducts were formed.

^gIsolated yields of 1H₂.

appropriate amounts of MeOH (entries 10, 11). Similarly, **2Zn-b** was demetallated with $Me_3SiBr-MeOH$ to yield $1H_2$ -b (entry 12).

The above demetallation of ZnTADAP with Me₃SiX–MeOH (X = Cl, Br) likely proceeded as follows. The HX molecule, generated in situ from Me₃SiX and MeOH, strongly interacts with the Zn–N bond via axial coordination of the halide ion to the zinc center of **2Zn**. Subsequently or simultaneously, the internal N atom of **2Zn** is protonated to release the zinc ion via metathesis. In the absence of MeOH, the trace amount of water remaining in the solvent might facilitate the hydrolysis of Me₃SiX to generate HX (entries 4 to 9). In HX aq solutions, the counter anions are likely solvated by water molecules and cannot effectively coordinate to the zinc center (entries 1 to 3). Unsuccessful demetallation by Me₃SiOTf indicated that coordination of the triflate ion was insufficient to enhance the reactivity of the Zn–N bond toward protons. The optimized synthesis procedure is described in section 4.

With the TADAP free bases in hand, complexation of **2H₂-a** with the silicon(IV) ion using Adler's method was examined (Scheme 2).¹³ Treatment of **2H₂-a** with HSiCl₃ in CH₂Cl₂ at room temperature afforded an inseparable mixture of silicon(IV) complexes of TADAP with different axial ligands. ¹H NMR and HRMS data of the crude product suggested that the axial ligands were hydroxy and/or chloride ions. To isolate



Scheme 2. Synthesis of SiF₂TADAP.

a single silicon(IV) complex, the resulting mixture was reacted with SbF₃ to convert all axial ligands to fluoride ions and then treated with AgPF₆ to convert the TADAP ligand to the 19 π -electron state. Finally, SiF₂TADAP radical cation **1Si-a** was isolated using silica-gel column chromatography. Reduction of **1Si-a** with cobaltocene (CoCp₂) in THF yielded high-purity SiF₂TADAP **2Si-a** in the 20 π -electron state, which was confirmed with ¹H and ¹⁹F{¹H} NMR spectra. **2Si-a** was found to be stable to hydrolysis and methanolysis. Oxidation of **1Si-a** with AgPF₆ in CD₂Cl₂ quantitatively produced SiF₂TADAP dication **3Si-a** (vide infra). However, **3Si-a** could not be isolated because it readily reduced to the 19 π -electron species under ambient conditions.

The crystal structure of **1Si-a** (CCDC Deposition Number: 2303271) is depicted in Fig. 1. The silicon center has an octahedral geometry with Si–N and Si–F bond lengths of 1.9347(15) to 1.9415(16) and 1.6292(11) Å, respectively. The Si–N bonds in **1Si-a** are slightly longer than those in the difluorosilicon(IV) complexes of 5,10,15,20-tetraarylporphyrins (aryl = *p*-tolyl, *p*-CF₃C₆H₄).¹⁴ It is worth noting that **1Si-a** has a highly flat DAP ring with a root mean square deviation of 0.043 Å (Supplementary Fig. S1).

Figure 2 shows the ¹H NMR spectra of **2Si-a** and **3Si-a**. The pyrrolic- β protons of **2Si-a** in C₆D₆ gave rise to peaks at 4.66 and 3.32 ppm, whereas those of **3Si-a** in CD₂Cl₂ gave rise to peaks at 9.07 and 8.80 ppm. These widely separated upfield and downfield shifts indicated the presence of substantial paratropic (20 π) and diatropic (18 π) ring currents, respectively. In the ¹⁹F NMR spectra of **2Si-a** and **3Si-a**, the axial fluorine signal appeared at -68.3 and -114.1 ppm (vs. CFCl₃), respectively. Similarly, these upfield and downfield shifts

reflected the effects of paratropic and diatropic ring currents, respectively. Therefore, the DAP rings of **2Si-a** and **3Si-a** exhibited antiaromaticity and aromaticity, respectively. The axial fluorine atoms of **3Si-a** were slightly less shielded than those of the difluorosilicon(IV) complex of 5,10,15,20-tetraphenylporphyrin (SiF₂TPP; $\delta_F = -121.4$ ppm vs. CFCl₃),¹⁵ which indicated that the diatropic ring-current effect of the DAP ring in **3Si-a** was slightly weaker than that of the porphyrin ring in SiF₂TPP. In the ²⁹Si NMR spectrum of **2Si-a**, a triplet signal appeared at -183.0 ppm (vs. TMS; $J_{Si-F} = 197$ Hz). The ²⁹Si resonance of **2Si-a** is shifted upfield by 90 ppm compared to that of antiaromatic Si(TPP)(py)₂ (-93 ppm),³ which may reflect the large difference in the electronic effects of the axial ligands (py = pyridine).

To gain insight into the ring-current effects of the TADAP and TPP π -electron systems, we calculated the nuclear independent chemical shift (NICS) at three/two positions in the π -planes of 2Si-m, 3Si-m, and SiF₂TPP, which were structurally optimized using the density functional theory (DFT) method (Supplementary Table S1 and Fig. S2). Owing to the paratropic ring current of the 20π -electron DAP ring, the calculated NICS(0) values at the a and b positions of 2Si-m were +6.82 and +7.09 ppm, respectively. The calculated NICS(0) values at the same a and b positions of 3Si-m were -17.20and -17.65 ppm, respectively, which were less negative than the corresponding value (-18.18 ppm) at the *a* position of SiF₂TPP. This indicated that the macrocyclic diatropic ringcurrent effect of the 18π SiF₂TADAP dication was slightly weaker than that of isoelectronic SiF₂TPP. This difference was attributed to the different current densities of these two 18π -electron systems. Furthermore, we calculated the



Fig. 1. ORTEP diagram (50% probability ellipsoids) and bond lengths of 1Si-a. Hydrogen atoms are omitted for clarity.



Fig. 2. ¹H NMR spectra of a) **2Si-a** in C_6D_6 and b) **3Si-a** in CD_2Cl_2 . Asterisks indicate residual solvent peaks.

¹⁹F chemical shifts of the three models at the DFT level with gauge-including atomic orbitals (Supplementary Table S2). Although there were discrepancies in the absolute values, the order of the calculated chemical shifts for 2Si-m (-105.1 ppm), 3Si-m (-162.8 ppm), and SiF₂TPP (-172.4 ppm) was identical to the order of the observed chemical shifts for the series of 2Si-a, 3Si-a, and SiF₂TPP (vide supra). Overall, both the NMR spectra and DFT calculations clarified the antiaromaticity and aromaticity of 20π -and 18π -electron SiF₂TADAPs, respectively.

The ESR spectra of 1Si-a in CH₂Cl₂ are shown in Supplementary Fig. S3. The hyperfine-coupling structure observed for 1Si-a as well as spin densities calculated for 1Si-mrevealed that an electron spin of this radical was efficiently delocalized over the entire DAP ring. The lack of hyperfine coupling with silicon and fluorine atoms indicated that the SiF₂ unit in the core simply affected the orbital energies of the TADAP π -radical.

As shown in Fig. 3, the UV/vis/NIR absorption spectra of 1Si-a, 2Si-a and 3Si-a in CH₂Cl₂ contained characteristic absorption bands corresponding to the 19 π -, 20 π -, and 18 π -electronic states of the TADAP skeleton, respectively. To reveal the nature of these π - π * electronic transitions, we carried out time-dependent DFT (TD-DFT) calculations of their models, and the results are summarized in



Fig. 3. UV/vis/NIR absorption spectra of SiF₂TADAPs in CH₂Cl₂. The spectrum of **3Si-a** was measured in the presence of a small amount of AgPF₆ and normalized to that of **1Si-a**.

Supplementary Table S3. The Q-like band of 3Si-a ($\lambda_{max} = 631 \text{ nm}$), corresponding to the HOMO-to-LUMO electronic transition, was significantly red-shifted and intensified compared with the Q band of SiF₂TPP ($\lambda_{max} = 521 \text{ nm}$). This trend was similar to that observed for the other metal(II) complexes (MTADAP vs. MTPP).

The redox potentials of **1Si-a** in CH₂Cl₂ were measured using cyclic voltammetry with Bu₄NPF₆ as the supporting electrolyte (Supplementary Fig. S4). The SiF₂TADAP π -electron system underwent three reversible redox processes at -1.81, -0.29, and +0.44 V vs. ferrocene/ferrocenium (Fc/Fc⁺), which were attributed to the 21 π /20 π , 20 π /19 π , and 19 π /18 π redox couples, respectively. These half-wave potentials were shifted toward the more positive side compared with the corresponding potentials of the zinc(II), nickel(II), and copper(II) complexes of the same TADAP ligand,¹⁰ suggesting that SiF₂ functioned as an electron-withdrawing unit. The orbital energies calculated using the DFT method supported this trend. Notably, the SiF₂ unit significantly contributed to stabilizing the antiaromatic 20 π -electron state of the DAP ring in air.

3. Conclusion

We developed a new method for the synthesis of free bases of TADAP from the corresponding zinc(II) complexes. Using Me₃SiBr–MeOH improved the previously reported method in terms of reaction efficiency and reproducibility. Furthermore, we successfully converted the free base to the first examples of difluorosilicon(IV) complexes of TADAP and characterized the structures of the complexes using spectroscopic techniques and DFT calculations. The ring-current effects of the TADAP ligand were investigated using ¹H and ¹⁹F NMR spectroscopy and NICS calculations, all of which revealed the antiaromaticity and aromaticity of the 20π - and 18π -electron DAP rings, respectively.

4. Experimental

Demetallation of ZnTADAP: **1Zn-a** (158 mg, 163 µmol) was dissolved in THF (5.0 mL) and reduced to **2Zn-a** with NaBH₄. After exchanging the solvent from THF to CH₂Cl₂ (4 mL), MeOH and Me₃SiBr (each, 30 equiv.) were added, and the resulting solution was stirred at room temperature for 5 h. As the crude product contained both 19π - and 20π -electron species, AgPF₆ was added to the product mixture, followed by treatment with an aqueous KPF₆ solution. The radical cation of free base **1H₂-a** was isolated in 98% yield by silica-gel column chromatography. For details, see the online supplementary material.

Supplementary data

Supplementary material is available at *Bulletin of the Chemical Society of Japan* online.

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